

| oducts | Home ▶ 2N6276 (#23538) 2N6276 (#23538) | | | | | | Related Links |
|--|--|----------------------|------------------|---------|-----------------|------|--|
| Product Directory Applications Directory Parametric Search | Overview Diagrams | | | | | | Technical support Sales Contacts Available Stock |
| | Electrical Rating | Symbol | Min | Тур | Max | Unit | Sales Contacts RFQ/Samples |
| | Collector to Emitter Saturation Voltage | V _{CE(sat)} | | | 3.00 | V | RFQ/Samples |
| | DC Current Gain | HFE | 30.00 | | 120.00 | | |
| | Maximum Electrical Rating | | | Min Typ | | Unit | |
| | Breakdown Voltage, Collector-Base (Emitter Open) | _ | /BR(CBO) | | 160.00 50.00 | V | |
| | Collector Current (dc) Collector-Emitter Voltage (Base Open) | | c | | 120.00 | V | |
| | Emitter-Base Voltage (Collector Open) | _ | / _{EBO} | | 6.00 | V | |
| | Power Dissipation, Total | | PT | | 250.00 | W | |
| | This part can be found in the following product Discretes > Transistors > BJT(BiPolar Junction Tra Non-Radiation Hardened Devices > Transistors > E | ansistor) 🕨 | PNP Transis | | NPN Transis | stor | |

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